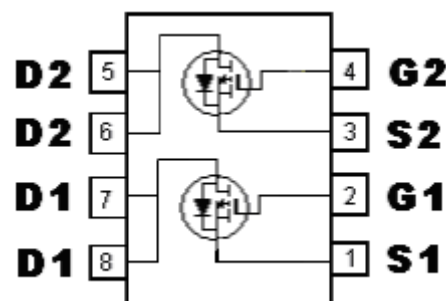
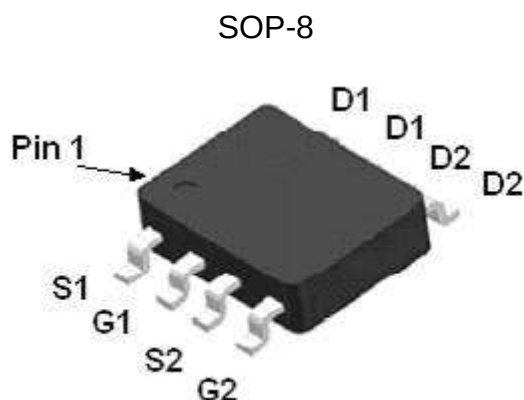


Dual P-Channel Enhancement Mode Power MOSFET

Features:

- Simple drive requirement
- Low on-resistance
- Fast switching speed
- Dual P-ch MOSFET package
- Pb-free lead plating & halogen-free package

BV_{DSS}	-30V
$I_D@V_{GS}=-10V, T_A=25\text{ }^{\circ}C$	-10.5A
$R_{DS(on)(MAX)}@V_{GS}=-10V, I_D=-12A$	8.7m Ω (typ.)
$R_{DS(on)(MAX)}@V_{GS}=-4.5V, I_D=-10A$	12.3m Ω (typ.)
$R_{DS(on)(MAX)}@V_{GS}=-3V, I_D=-5A$	22.4m Ω (typ.)



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KSCA9D0B03	SOP-8 (Pb-free lead plating and halogen-free package)	2500 pcs / tape & reel

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current @V _{GS} =-10V, T _C =25 °C	I _D	-18.6	A
Continuous Drain Current @V _{GS} =-10V, T _C =100 °C		-13.2	
Continuous Drain Current @V _{GS} =-10V, T _A =25 °C		-10.5	
Continuous Drain Current @V _{GS} =-10V, T _A =70 °C		-8.8	
Pulsed Drain Current (Note 1)	I _{DM}	-82	
Power Dissipation	P _D	2.4	W
		1.3	
Operating Junction and Storage Temperature Range	T _j ; T _{stg}	-55~+175	°C

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R _{th,j-c}	20	°C/W
Thermal Resistance, Junction-to-ambient, max	R _{th,j-a}	62.5 *3	

- Note : 1. Pulse width limited by maximum junction temperature
2. Duty cycle ≤ 1%
3. Surface mounted on 1 in² copper pad of FR-4 board, 125°C/W when mounted on minimum copper pad

Characteristics (T_j=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	-30	-	-	V	V _{GS} =0V, I _D =-250μA
V _{GS(th)}	-0.8	-	-1.8		V _{DS} = V _{GS} , I _D =-250μA
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V
I _{DSS}	-	-	-1	μA	V _{DS} = -24V, V _{GS} = 0V
	-	-	-10		V _{DS} = -24V, V _{GS} = 0V, T _j =125°C
*R _{DS(ON)} *1	-	8.7	13	mΩ	V _{GS} = -10V, I _D =-12A
	-	12.3	20		V _{GS} = -4.5V, I _D =-10A
	-	22.4	57		V _{GS} = -3V, I _D =-5A
G _{FS} *1	-	24	-	S	V _{DS} = -5V, I _D =-10A
Dynamic					
Q _g *1, 2	-	51.1	-	nC	V _{DS} =-15V, I _D =-12A, V _{GS} =-10V
Q _{gs} *1, 2	-	6.1	-		
Q _{gd} *1, 2	-	10.5	-		
t _{d(ON)} *1, 2	-	12	-	ns	V _{DS} =-15V, I _D =-12A, V _{GS} =-10V, R _G =1Ω
t _r *1, 2	-	9.6	-		
t _{d(OFF)} *1, 2	-	70.6	-		
t _f *1, 2	-	11	-		

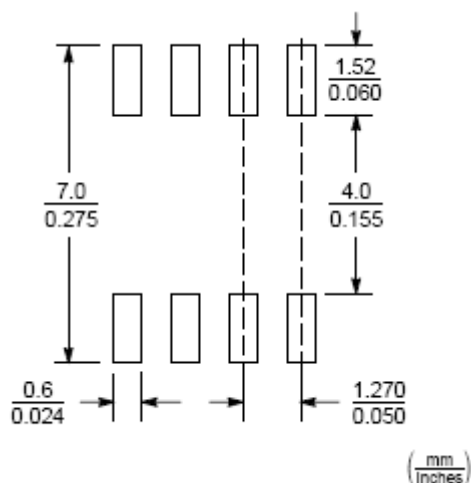
Ciss	-	2343	-	pF	V _{GS} =0V, V _{DS} =-25V, f=1MHz
Coss	-	238	-		
Crss	-	198	-		
Rg	-	5.3	-	Ω	f=1MHz
Source-Drain Diode					
I _S *1	-	-	-2.3	A	
I _{SM} *3	-	-	-9.2		
V _{SD} *1	-	-0.75	-1	V	I _S = -2.1A, V _{GS} =0V
trr *1	-	19.2	-	ns	I _F = -2.1A, dI _F /dt=100A/μs
Qrr *1	-	8.4	-	nC	

Note : *1.Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

*2.Independent of operating temperature

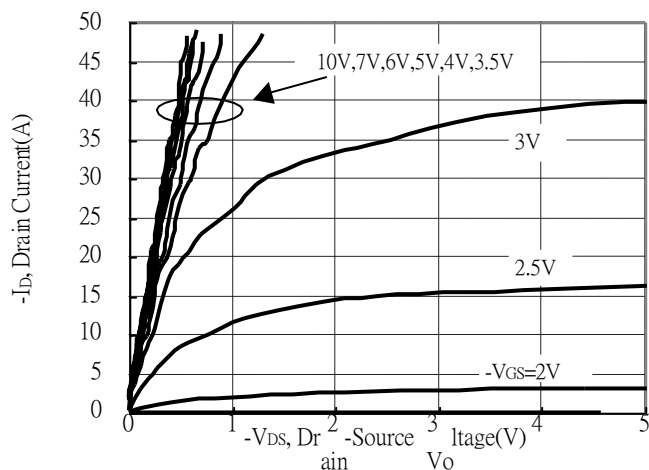
*3.Pulse width limited by maximum junction temperature.

Recommended Soldering Footprint

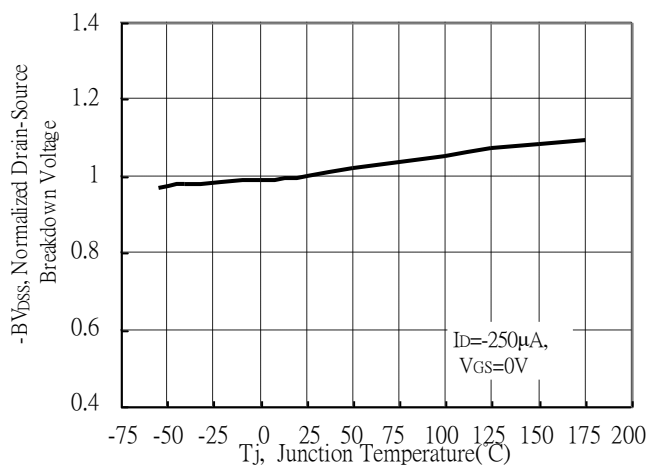


Typical Characteristics

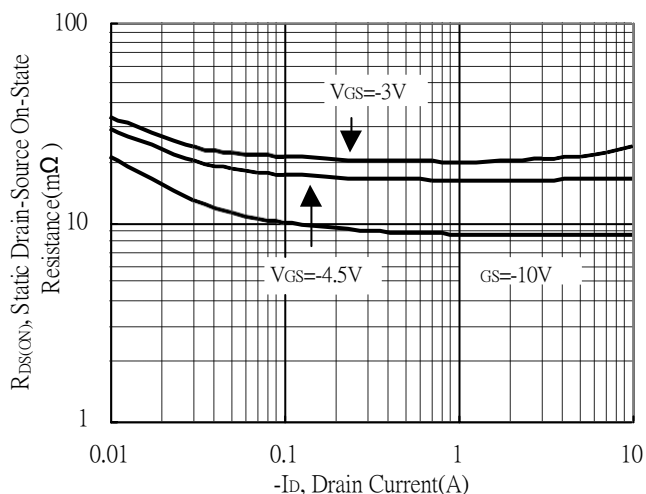
Typical Output Characteristics



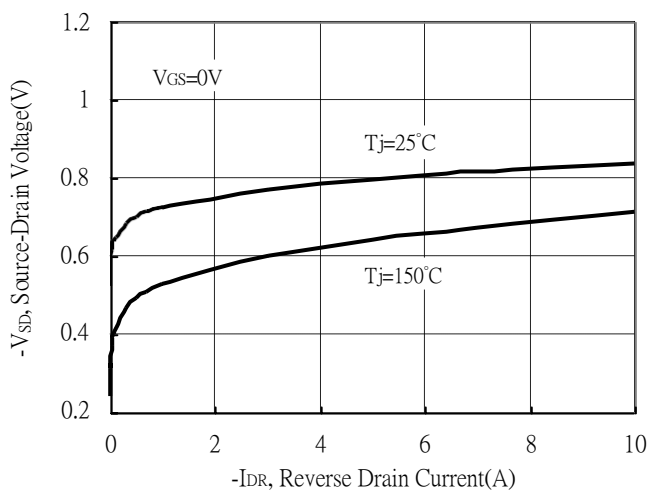
Breakdown Voltage vs Ambient Temperature



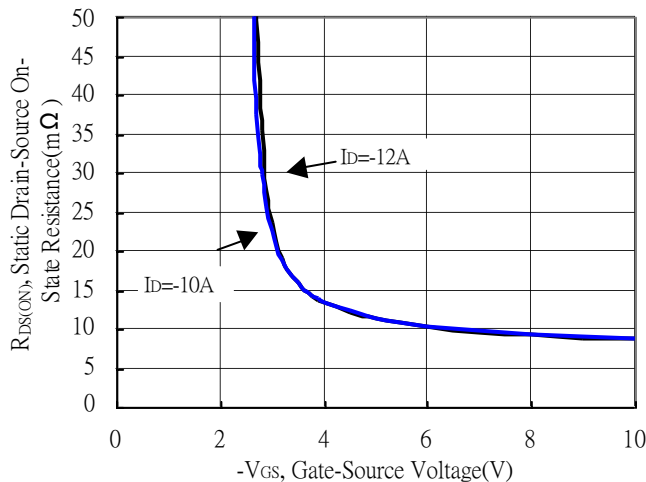
Static Drain-Source On-State resistance vs Drain Current



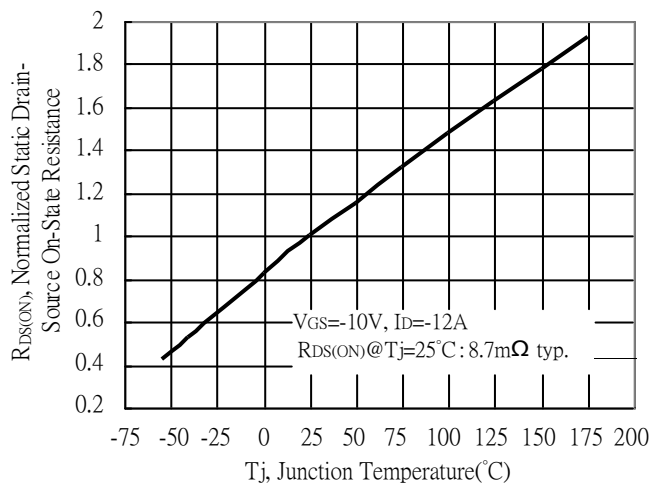
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

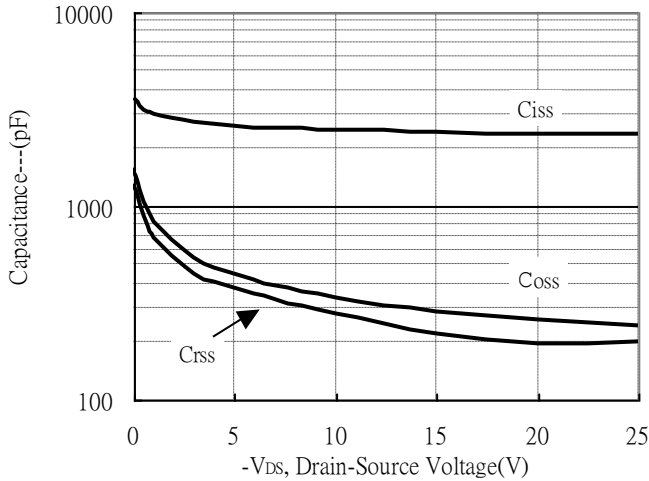


Drain-Source On-State Resistance vs Junction Temperature

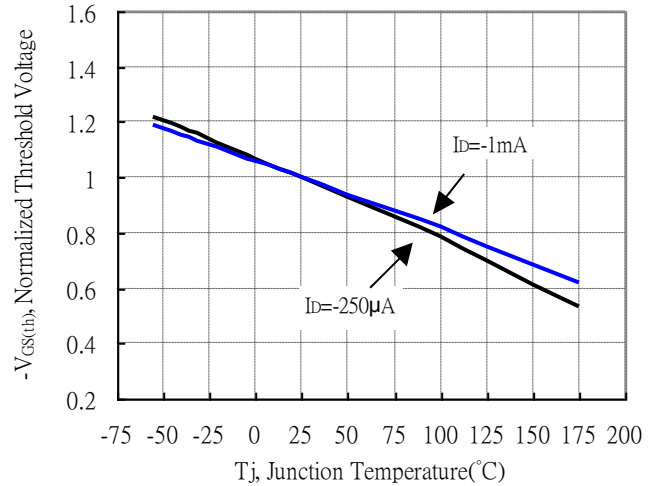


Typical Characteristics(Cont.)

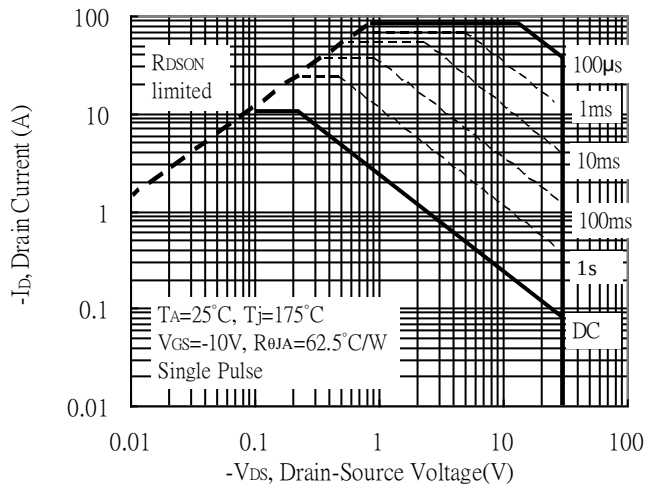
Capacitance vs Drain-to-Source Voltage



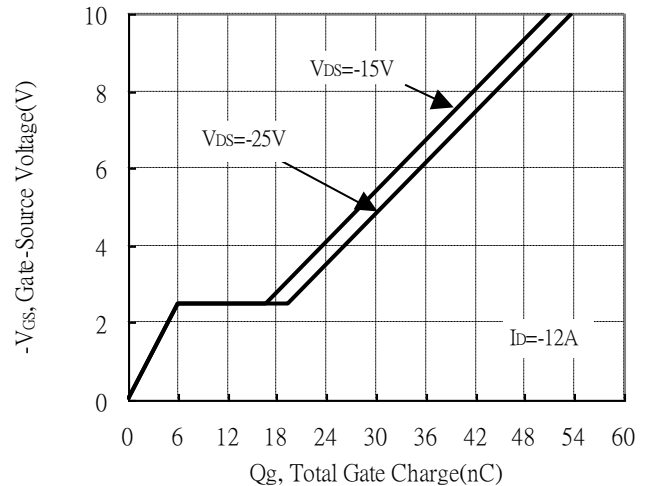
Threshold Voltage vs Junction Temperature



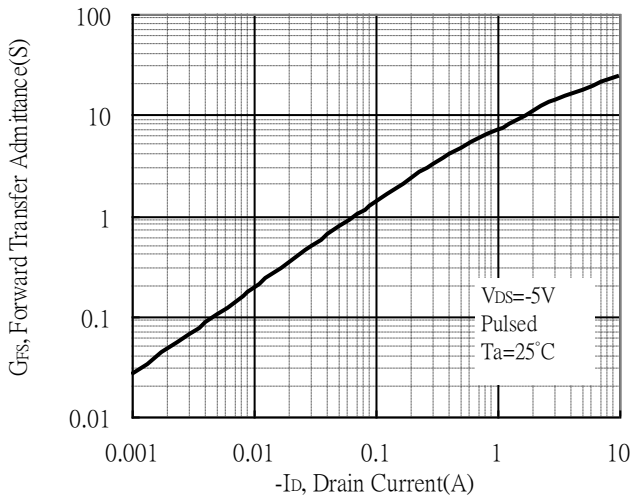
Maximum Safe Operating Area



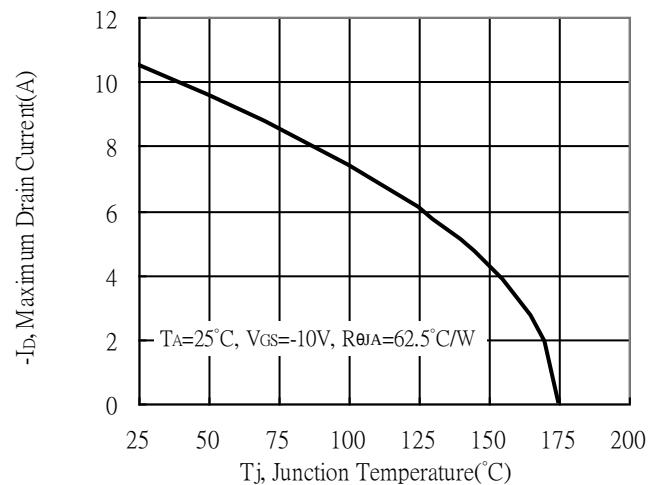
Gate Charge Characteristics



Forward Transfer Admittance vs Drain Current

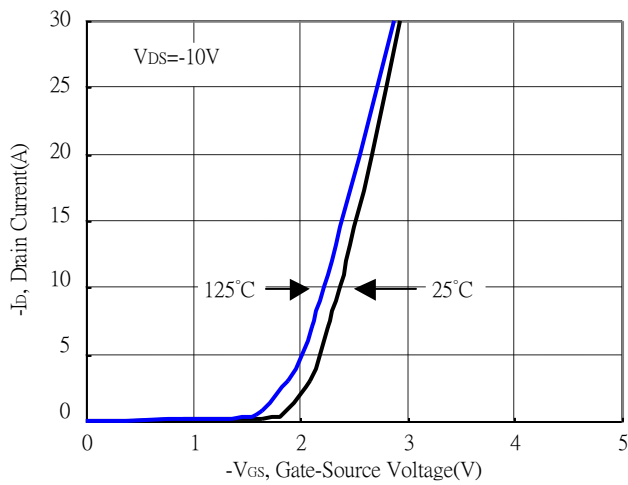


Maximum Drain Current vs Junction Temperature

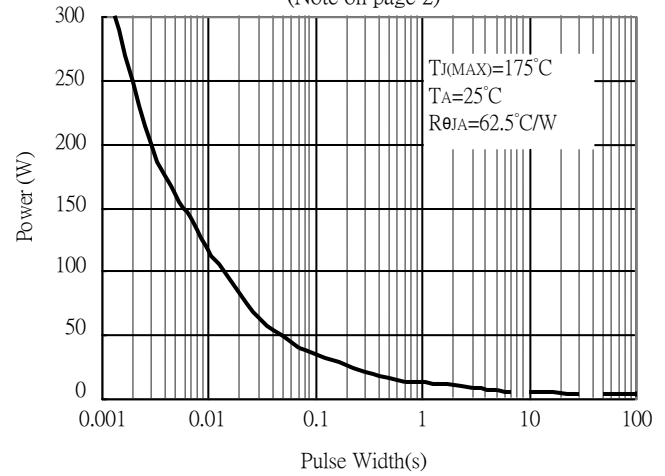


Typical Characteristics(Cont.)

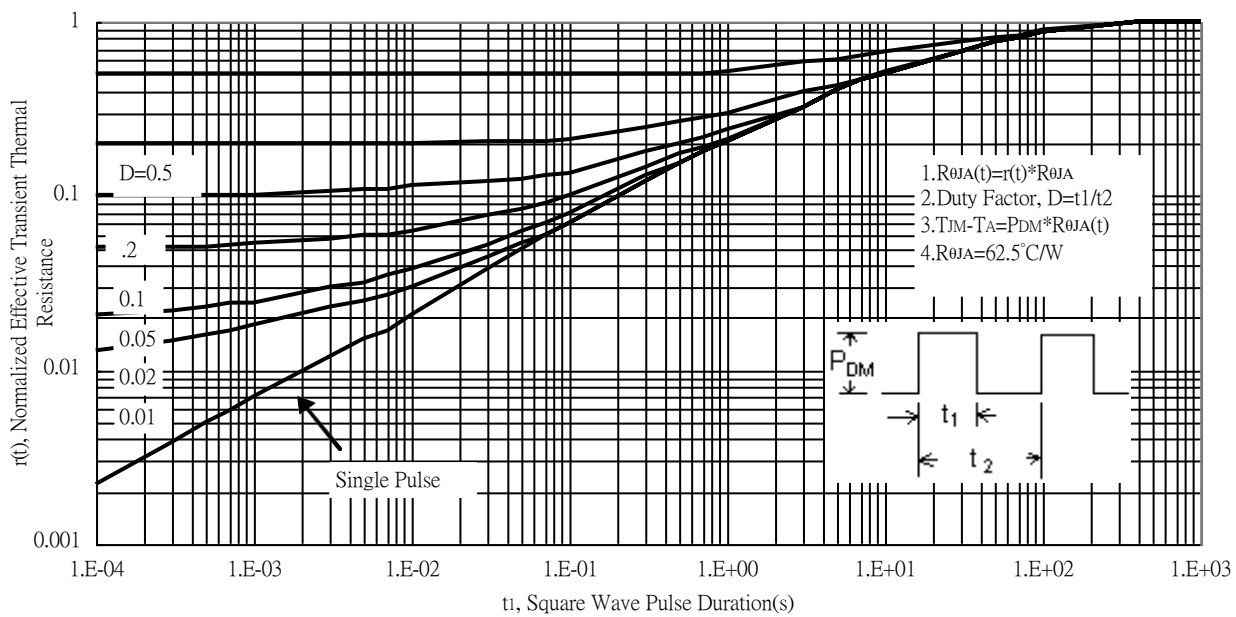
Typical Transfer Characteristics



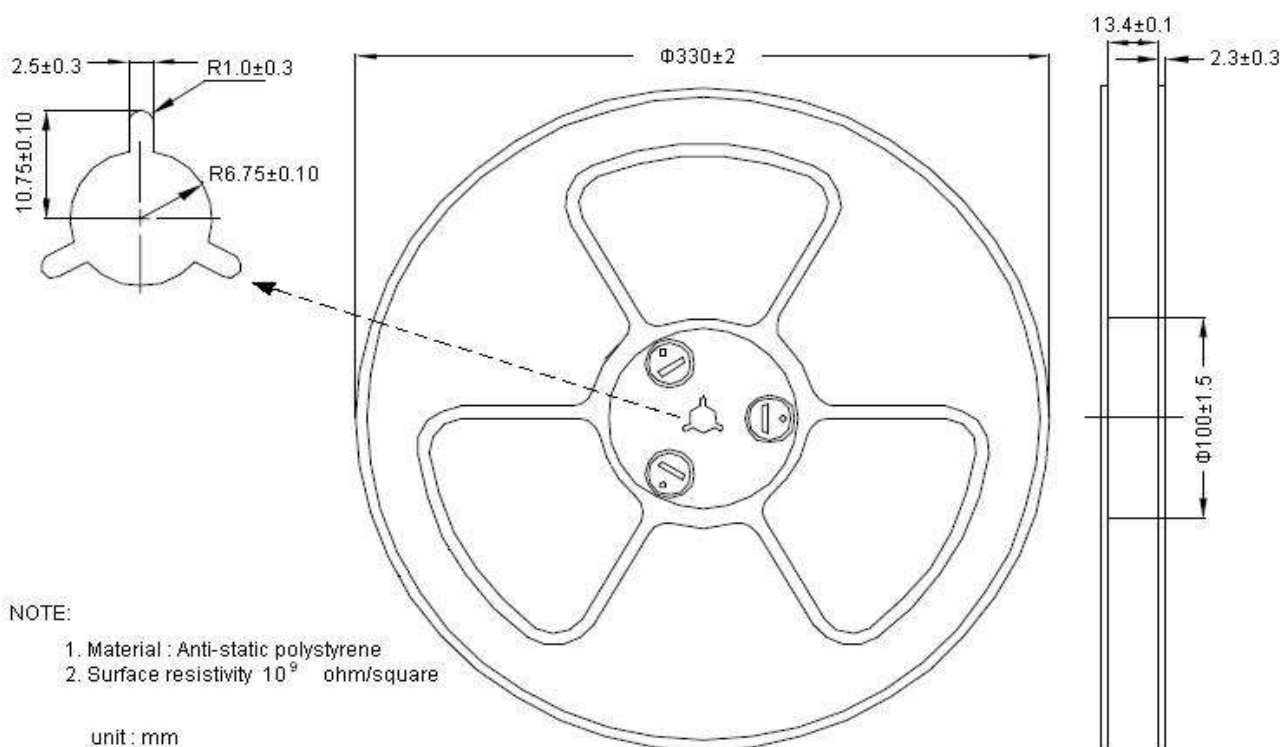
Single Pulse Power Rating, Junction to Ambient
 (Note on page 2)



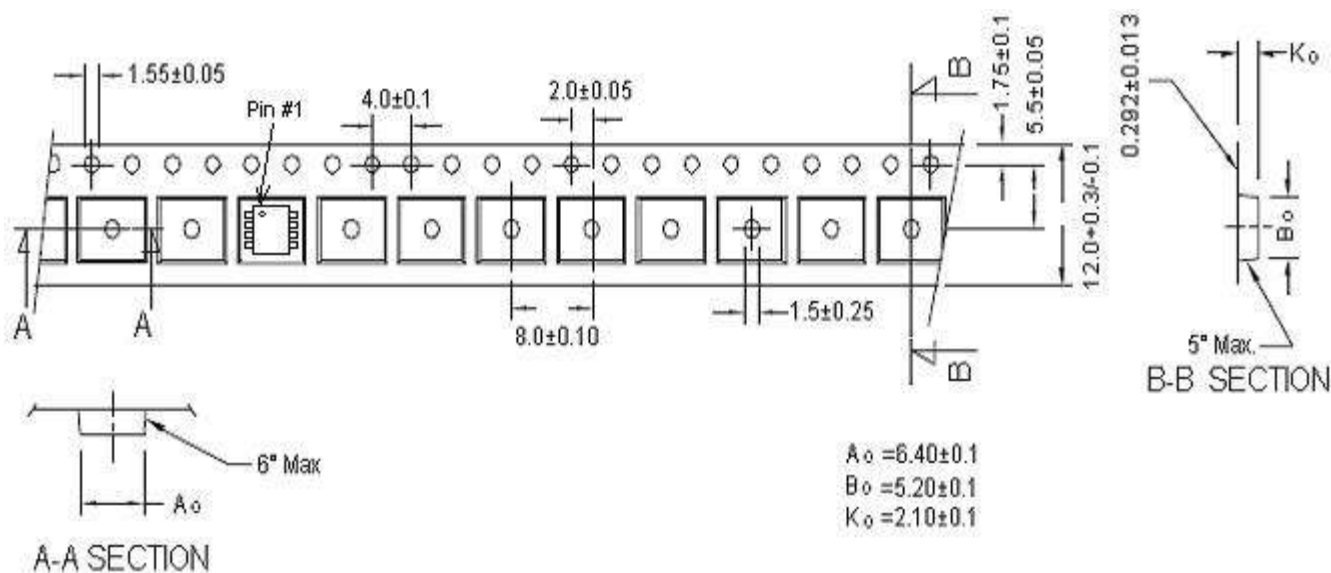
Transient Thermal Response Curves



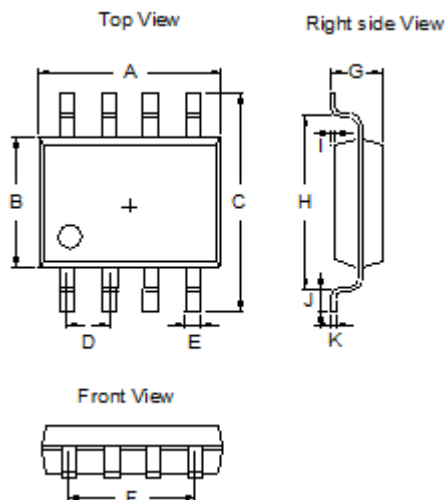
Reel Dimension



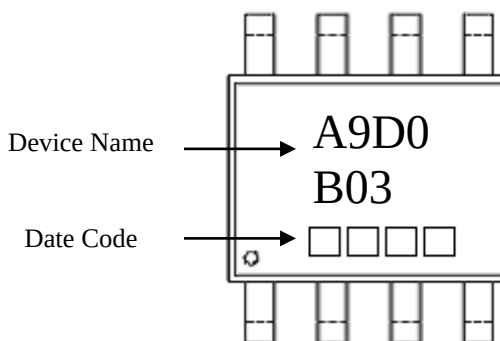
Carrier Tape Dimension



SOP-8 Dimension



Marking:



Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year

2nd code : month code, Jan→A, Feb→B, Mar→C, Apr→D,

May→E, Jun→F, Jul→G, Aug→H, Sep→J, Oct→K,

Nov→L, Dec→M

3rd and 4th codes : prodcution serial number, 01~99

8-Lead SOP-8 Plastic Package

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1890	0.2007	4.80	5.10	G	0.0531	0.0689	1.35	1.75
B	0.1496	0.1654	3.80	4.20	H	0.1889	0.2007	4.80	5.10
C	0.2283	0.2441	5.80	6.20	I	0.0098	REF	0.25	REF
D	0.0480	0.0519	1.22	1.32	J	0.0118	0.0366	0.30	0.93
E	0.0138	0.0200	0.35	0.51	K	0.0074	0.0098	0.19	0.25
F	0.1472	0.1527	3.74	3.88					